74ALVC164245

16-bit dual supply translating transceiver; 3-state

Rev. 9 — 12 November 2018

Product data sheet

1. General description

The 74ALVC164245 is a high-performance, low-power, low-voltage, Si-gate CMOS device, superior to most advanced CMOS compatible TTL families.

The 74ALVC164245 is a 16-bit (dual octal) dual supply translating transceiver featuring non-inverting 3-state bus compatible outputs in both send and receive directions. It is designed to interface between a 3 V and 5 V bus in a mixed 3 V and 5 V supply environment.

This device can be used as two 8-bit transceivers or one 16-bit transceiver.

The direction control inputs (1DIR and 2DIR) determine the direction of the data flow. nDIR (active HIGH) enables data from nAn ports to nBn ports. nDIR (active LOW) enables data from nBn ports to nAn ports. The output enable inputs (1 $\overline{\text{OE}}$ and 2 $\overline{\text{OE}}$), when HIGH, disable both nAn and nBn ports by placing them in a high-impedance OFF-state. Pins nAn, n $\overline{\text{OE}}$ and nDIR are referenced to $V_{\text{CC(A)}}$ and pins nBn are referenced to $V_{\text{CC(B)}}$.

In suspend mode, when one of the supply voltages is zero, there will be no current flow from the non-zero supply towards the zero supply. The nAn-outputs must be set 3-state and the voltage on the A-bus must be smaller than V_{diode} (typical 0.7 V). $V_{\text{CC(B)}} \ge V_{\text{CC(A)}}$ (except in suspend mode).

2. Features and benefits

- 5 V tolerant inputs/outputs for interfacing with 5 V logic
- Wide supply voltage range:
 - 3 V port (V_{CC(A)}): 1.5 V to 3.6 V
 - 5 V port (V_{CC(B)}): 1.5 V to 5.5 V
- CMOS low power consumption
- Direct interface with TTL levels
- Control inputs voltage range from 2.7 V to 5.5 V
- Inputs accept voltages up to 5.5 V
- High-impedance outputs when V_{CC(A)} or V_{CC(B)} = 0 V
- Complies with JEDEC standard JESD8-B/JESD36
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Ordering information

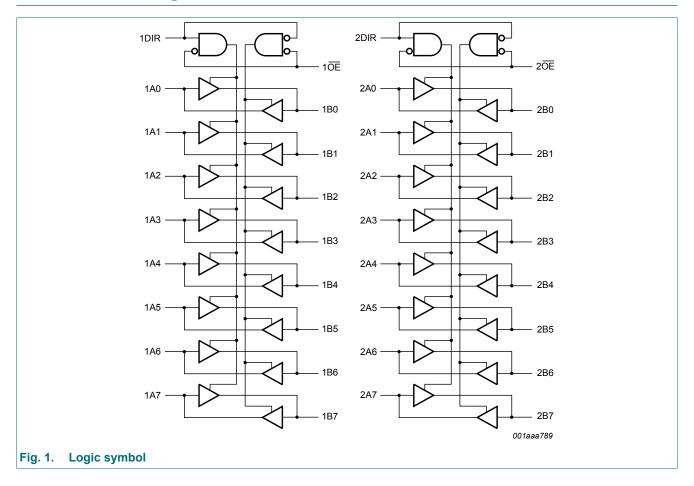
Table 1. Ordering information

Type number	Package							
	Temperature range	Name	Description	Version				
74ALVC164245DL	-40 °C to +125 °C	SSOP48	plastic shrink small outline package; 48 leads; body width 7.5 mm	SOT370-1				
74ALVC164245DGG	-40 °C to +125 °C	TSSOP48	plastic thin shrink small outline package; 48 leads; body width 6.1 mm	SOT362-1				

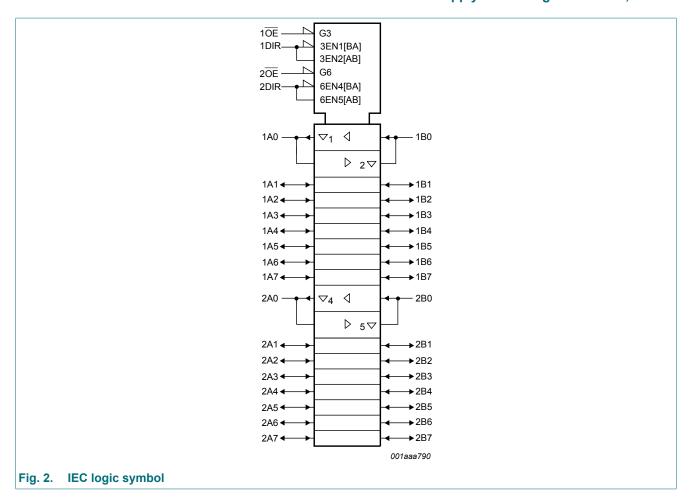


16-bit dual supply translating transceiver; 3-state

4. Functional diagram



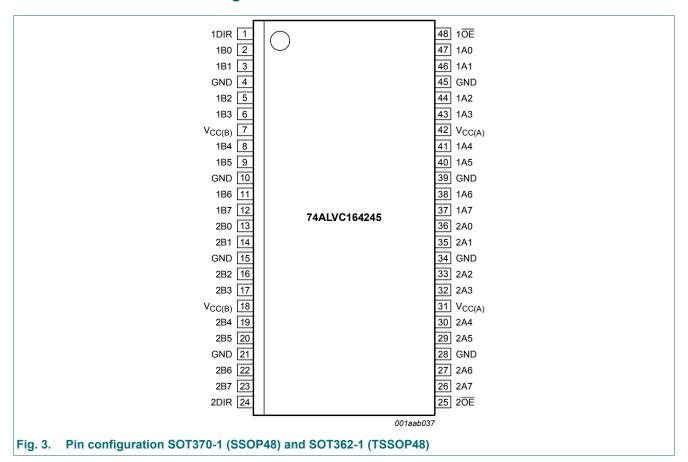
16-bit dual supply translating transceiver; 3-state



16-bit dual supply translating transceiver; 3-state

5. Pinning information

5.1. Pinning



5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
1DIR, 2DIR	1, 24	direction control input
1B0, 1B1, 1B2, 1B3, 1B4, 1B5, 1B6, 1B7	2, 3, 5, 6, 8, 9, 11, 12	data input/output
2B0, 2B1, 2B2, 2B3, 2B4, 2B5, 2B6, 2B7	13, 14, 16, 17, 19, 20, 22, 23	data input/output
GND	4, 10, 15, 21, 28, 34, 39, 45	ground (0 V)
$V_{CC(B)}$	7, 18	supply voltage B (5 V bus)
10E, 20E	48, 25	output enable input (active LOW)
1A0, 1A1, 1A2, 1A3, 1A4, 1A5, 1A6, 1A7	47, 46, 44, 43, 41, 40, 38, 37	data input/output
2A0, 2A1, 2A2, 2A3, 2A4, 2A5, 2A6, 2A7	36, 35, 33, 32, 30, 29, 27, 26	data input/output
V _{CC(A)}	31, 42	supply voltage A (3 V bus)

6. Functional description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

•		Outputs		
ŌE nDIR		nAn	nBn	
L	L	nAn = nBn	inputs	
L	Н	inputs	nBn = nAn	
Н	X	Z	Z	

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC(B)}	supply voltage B	$V_{CC(B)} \ge V_{CC(A)}$		-0.5	+6.0	V
V _{CC(A)}	supply voltage A	$V_{CC(B)} \ge V_{CC(A)}$		-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V		-50	-	mA
V _I	input voltage		[1]	-0.5	+6.0	V
V _{I/O}	input/output voltage			-0.5	V _{CC} + 0.5	V
I _{OK}	output clamping current	$V_O > V_{CC}$ or $V_O < 0$ V		-	±50	mA
Vo	output voltage	output HIGH or LOW	[1]	-0.5	V _{CC} + 0.5	V
		output 3-state	[1]	-0.5	+6.0	V
I _{O(sink/source)}	output sink or source current	$V_O = 0 V \text{ to } V_{CC}$		-	±50	mA
I _{CC}	supply current			-	100	mA
I _{GND}	ground current			-100	-	mA
T _{stg}	storage temperature			-65	+150	°C
Tj	junction temperature		[2]	-	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[3]	-	500	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^[2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

^[3] Above 60 °C the value of Ptot derates linearly with 5.5 mW/K.

16-bit dual supply translating transceiver; 3-state

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC(B)}	supply voltage B	$V_{CC(B)} \ge V_{CC(A)}$				
		maximum speed performance	2.7	-	5.5	V
		low-voltage applications	1.5	-	5.5	V
V _{CC(A)}	supply voltage A	$V_{CC(B)} \ge V_{CC(A)}$				
		maximum speed performance	2.7	-	3.6	V
		low-voltage applications	1.5	-	3.6	V
VI	input voltage	control inputs: nOE and nDIR	0	-	5.5	V
V _{I/O} in	input/output voltage	nAn port	0	-	V _{CC(A)}	V
		nBn port	0	-	V _{CC(B)}	V
Vo	output voltage	nAn port	0	-	V _{CC(A)}	V
		nBn port	0	-	V _{CC(B)}	V
T _{amb}	ambient temperature		-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC(A)} = 2.7 V to 3.0 V	0	-	20	ns/V
		V _{CC(A)} = 3.0 V to 3.6 V	0	-	10	ns/V
		V _{CC(B)} = 3.0 V to 4.5 V	0	-	20	ns/V
		V _{CC(B)} = 4.5 V to 5.5 V	0	-	10	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	T _{amb} =	-40 °C to +8	85 °C	T _{amb} = -40 °C to +125 °C		Unit
			Min	Typ [1]	Max	Min	Max	
V_{IH}	HIGH-level	nBn port						
input voltage	V _{CC(B)} = 3.0 V to 5.5 V	2.0	-	-	2.0	-	V	
		nAn port, nOE and nDIR						
		V _{CC(A)} = 3.0 V to 3.6 V	2.0	-	-	2.0	-	V
		$V_{CC(A)} = 2.3 \text{ V to } 2.7 \text{ V}$ [2	1.7	-	-	1.7	-	V
V_{IL}	LOW-level	nBn port						
	input voltage	$V_{CC(B)} = 4.5 \text{ V to } 5.5 \text{ V}$ [2]] -	-	8.0	-	0.8	V
		$V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$ [2]] -	-	0.7	-	0.7	V
		nAn port, nOE and nDIR						
		V _{CC(A)} = 3.0 V to 3.6 V	-	-	0.8	-	0.8	V
		$V_{CC(A)} = 2.3 \text{ V to } 2.7 \text{ V}$ [2]] -	-	0.7	-	0.7	V

16-bit dual supply translating transceiver; 3-state

Symbol	Parameter	Conditions	T _{amb} = -4	0 °C to +8	85 °C	T _{amb} = -40 °C to +125 °C		Unit
			Min	Typ [1]	Max	Min	Max	
V _{OH}	HIGH-level	nBn port; V _I = V _{IH} or V _{IL}						
	output voltage	I _O = -24 mA; V _{CC(B)} = 4.5 V	V _{CC(B)} - 0.8	-	-	V _{CC(B)} - 1.2	-	V
		I _O = -12 mA; V _{CC(B)} = 4.5 V	V _{CC(B)} - 0.5	-	-	V _{CC(B)} - 0.8	-	V
		I_{O} = -18 mA; $V_{CC(B)}$ = 3.0 V	V _{CC(B)} - 0.8	-	-	V _{CC(B)} - 1.0	-	V
		I_{O} = -100 μ A; $V_{CC(B)}$ = 3.0 V	V _{CC(B)} - 0.2	V _{CC(B)}	-	V _{CC(B)} - 0.3	-	V
		nAn port; V _I = V _{IH} or V _{IL}						
		I _O = -24 mA; V _{CC(A)} = 3.0 V	V _{CC(A)} - 0.7	-	-	V _{CC(A)} - 1.0	-	V
	I_{O} = -100 μ A; $V_{CC(A)}$ = 3.0 V	V _{CC(A)} - 0.2	-	-	V _{CC(A)} - 0.3	-	V	
		I_{O} = -12 mA; $V_{CC(A)}$ = 2.7 V	V _{CC(A)} - 0.5	-	-	V _{CC(A)} - 0.8	-	V
		I_{O} = -8 mA; $V_{CC(A)}$ = 2.3 V	V _{CC(A)} - 0.6	-	-	V _{CC(A)} - 0.6	-	V
		$I_O = -100 \mu A; V_{CC(A)} = 2.3 V$	V _{CC(A)} - 0.2	V _{CC(A)}	-	V _{CC(A)} - 0.3	-	V
V_{OL}	LOW-level	nBn port; V _I = V _{IH} or V _{IL}	,			, ,		
	output voltage	I _O = 24 mA; V _{CC(B)} = 4.5 V	-	-	0.55	-	0.60	V
		I _O = 12 mA; V _{CC(B)} = 4.5 V	-	-	0.40	-	0.80	V
		I _O = 100 μA; V _{CC(B)} = 4.5 V	-	-	0.20	-	0.30	V
		I _O = 18 mA; V _{CC(B)} = 3.0 V	-	-	0.55	-	0.80	V
		I _O = 100 μA; V _{CC(B)} = 3.0 V	-	-	0.20	-	0.30	V
		nAn port; V _I = V _{IH} or V _{IL}						
		I _O = 24 mA; V _{CC(A)} = 3.0 V	-	-	0.55	-	0.80	V
		I _O = 100 μA; V _{CC(A)} = 3.0 V	-	-	0.20	-	0.30	V
		I _O = 12 mA; V _{CC(A)} = 2.7 V	-	-	0.40	-	0.60	V
		I _O = 12 mA; V _{CC(A)} = 2.3 V	-	-	0.60	-	0.60	V
		I _O = 100 μA; V _{CC(A)} = 2.3 V	-	-	0.20	-	0.20	V
l _l	input leakage current	V _I = 5.5 V or GND	-	±0.1	±5	-	±10	μΑ
I _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND [3]	-	±0.1	±10	-	±20	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A	-	0.1	40	-	80	μΑ
ΔI _{CC}	additional supply current	per control pin; $V_I = V_{CC} - 0.6 \text{ V}$; [4] $I_O = 0 \text{ A}$	-	5	500	-	5000	μA
C _I	input capacitance		-	4.0	-	-	-	pF
C _{I/O}	input/output capacitance	nAn and nBn port	-	5.0	-	-	-	pF

^[1] All typical values are measured at $V_{CC(B)}$ = 5.0 V, $V_{CC(A)}$ = 3.3 V and T_{amb} = 25 °C. [2] If $V_{CC(A)}$ < 2.7 V, the switching levels at all inputs are not TTL compatible. [3] For transceivers, the parameter I_{OZ} includes the input leakage current.

^[4] $V_{CC(A)} = 2.7 \text{ V}$ to 3.6 V: other inputs at $V_{CC(A)}$ or GND; $V_{CC(B)} = 4.5 \text{ V}$ to 5.5 V: other inputs at $V_{CC(B)}$ or GND.

10. Dynamic characteristics

Table 7. Dynamic characteristics

GND = 0 V; $t_r = t_f \le 2.5$ ns; $C_L = 50$ pF; for test circuit see Fig. 6.

Symbol	Parameter	Conditions		T _{amb} :	= -40 °C to -	+85 °C	T _{ar}	Unit	
				Min	Typ [1]	Max	Min	Max	
t _{pd}	propagation	nAn to nBn; see Fig. 4	[2]						
	delay	$V_{CC(A)} = 2.3 \text{ V to } 2.7 \text{ V};$ $V_{CC(B)} = 3.0 \text{ V to } 3.6 \text{ V}$		1.5	3.3	7.6	1.5	9.5	ns
		$V_{CC(A)} = 2.7 \text{ V};$ $V_{CC(B)} = 4.5 \text{ V to } 5.5 \text{ V}$		1.0	3.0	5.9	1.0	7.5	ns
		$V_{CC(A)}$ = 3.0 V to 3.6 V; $V_{CC(B)}$ = 4.5 V to 5.5 V		1.0	2.9	5.8	1.0	7.5	ns
		nBn to nAn; see Fig. 4	[2]						
		V _{CC(A)} = 2.3 V to 2.7 V; V _{CC(B)} = 3.0 V to 3.6 V		1.0	3.0	7.6	1.0	9.5	ns
	$V_{CC(A)} = 2.7 \text{ V};$ $V_{CC(B)} = 4.5 \text{ V to } 5.5 \text{ V}$		1.0	4.3	6.7	1.0	8.5	ns	
	$V_{CC(A)} = 3.0 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 4.5 \text{ V to } 5.5 \text{ V}$		1.2	2.5	5.8	1.2	7.5	ns	
t _{en}	enable time	nOE to nBn; see Fig. 5	[3]						
		V _{CC(A)} = 2.3 V to 2.7 V; V _{CC(B)} = 3.0 V to 3.6 V		1.5	4.1	11.5	1.5	14.5	ns
		$V_{CC(A)} = 2.7 \text{ V};$ $V_{CC(B)} = 4.5 \text{ V to } 5.5 \text{ V}$		1.5	3.6	9.2	1.5	11.5	ns
		$V_{CC(A)} = 3.0 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 4.5 \text{ V to } 5.5 \text{ V}$		1.0	3.2	8.9	1.0	12.0	ns
		nOE to nAn; see Fig. 5	[3]						
		V _{CC(A)} = 2.3 V to 2.7 V; V _{CC(B)} = 3.0 V to 3.6 V		1.5	4.6	12.3	1.5	15.5	ns
		V _{CC(A)} = 2.7 V; V _{CC(B)} = 4.5 V to 5.5 V		1.5	4.3	9.3	1.5	12.0	ns
		$V_{CC(A)}$ = 3.0 V to 3.6 V; $V_{CC(B)}$ = 4.5 V to 5.5 V		1.0	3.2	8.9	1.0	11.5	ns
t _{dis}	disable time	nOE to nBn; see Fig. 5	[4]						-
		V _{CC(A)} = 2.3 V to 2.7 V; V _{CC(B)} = 3.0 V to 3.6 V		2.0	2.7	10.5	2.0	13.5	ns
		$V_{CC(A)} = 2.7 \text{ V};$ $V_{CC(B)} = 4.5 \text{ V to } 5.5 \text{ V}$		2.5	4.6	9.0	2.5	11.5	ns
		$V_{CC(A)} = 3.0 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 4.5 \text{ V to } 5.5 \text{ V}$		2.1	4.9	8.6	2.1	11.0	ns
		nOE to nAn; see Fig. 5	[4]						
		V _{CC(A)} = 2.3 V to 2.7 V; V _{CC(B)} = 3.0 V to 3.6 V		1.0	2.7	9.3	1.0	12.0	ns
		V _{CC(A)} = 2.7 V; V _{CC(B)} = 4.5 V to 5.5 V		1.5	3.5	9.0	1.5	11.5	ns
		V _{CC(A)} = 3.0 V to 3.6 V; V _{CC(B)} = 4.5 V to 5.5 V		2.0	3.2	8.6	2.0	11.0	ns

16-bit dual supply translating transceiver; 3-state

Symbol	Parameter	Conditions		T _{amb} = -40 °C to +85 °C			T _{amb} = -40 °C to +125 °C		Unit
				Min	Typ [1]	Max	Min	Max	
C _{PD}	power dissipation capacitance	5 V port: nAn to nBn; V_I = GND to V_{CC} ; $V_{CC(B)}$ = 5 V; $V_{CC(A)}$ = 3.3 V	[5]						
		outputs enabled		-	30	-	-	-	pF
		outputs disabled		-	15	-	-	-	pF
		3 V port: nBn to nAn; V_I = GND to V_{CC} ; $V_{CC(B)}$ = 5 V; $V_{CC(A)}$ = 3.3 V	[5]						
		outputs enabled		-	40	-	-	-	pF
		outputs disabled		-	5	-	-	-	pF

- All typical values are measured at nominal voltage for $V_{CC(B)}$ and $V_{CC(A)}$ and at T_{amb} = 25 °C.
- t_{pd} is the same as t_{PLH} and t_{PHL} .
- [3] ten is the same as tPZL and tPZH.
- t_{dis} is the same as t_{PLZ} and t_{PHZ} . C_{PD} is used to determine the dynamic power dissipation (P_D in μW). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_1 \times V_{CC}^2 \times f_0)$$
 where:

 f_i = input frequency in MHz;

fo = output frequency in MHz;

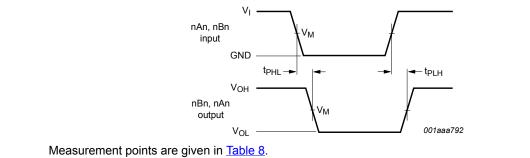
C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of outputs.

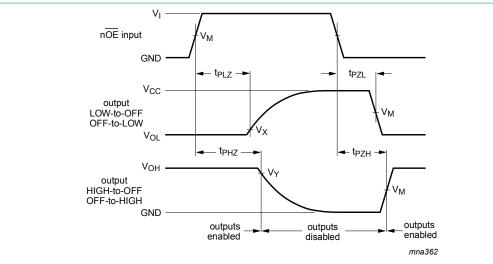
10.1. Waveforms and test circuit



V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Input (nAn, nBn) to output (nBn, nAn) propagation delays Fig. 4.

16-bit dual supply translating transceiver; 3-state



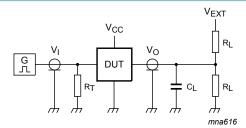
Measurement points are given in Table 8.

 $\ensuremath{V_{OL}}$ and $\ensuremath{V_{OH}}$ are typical output voltage levels that occur with output load.

Fig. 5. 3-state enable and disable times

Table 8. Measurement points

Direction	Supply voltage		Input		Output						
	V _{CC(A)}	V _{CC(B)}	Vı	V _M	V _M	V _X	V _Y				
nAn port to nBn port	2.3 V to 2.7 V	2.7 V to 3.6 V	$V_{CC(A)}$	$0.5 \times V_{CC(A)}$	1.5 V	$V_{OL(B)} + 0.3 V$	V _{OH(B)} - 0.3 V				
nBn port to nAn port	2.3 V to 2.7 V	2.7 V to 3.6 V	2.7 V	1.5 V	0.5 × V _{CC(A)}	V _{OL(A)} + 0.15 V	V _{OH(A)} - 0.15 V				
nAn port to nBn port	2.7 V to 3.6 V	4.5 V to 5.5 V	2.7 V	1.5 V	$0.5 \times V_{CC(B)}$	$0.2 \times V_{CC(B)}$	$0.8 \times V_{CC(B)}$				
nBn port to nAn port	2.7 V to 3.6 V	4.5 V to 5.5 V	3.0 V	1.5 V	1.5 V	V _{OL(A)} + 0.3 V	V _{OH(A)} - 0.3 V				



Test data is given in Table 9.

Definitions for test circuit:

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

 R_L = Load resistance.

Fig. 6. Test circuit for measuring switching times

Table 9. Test data

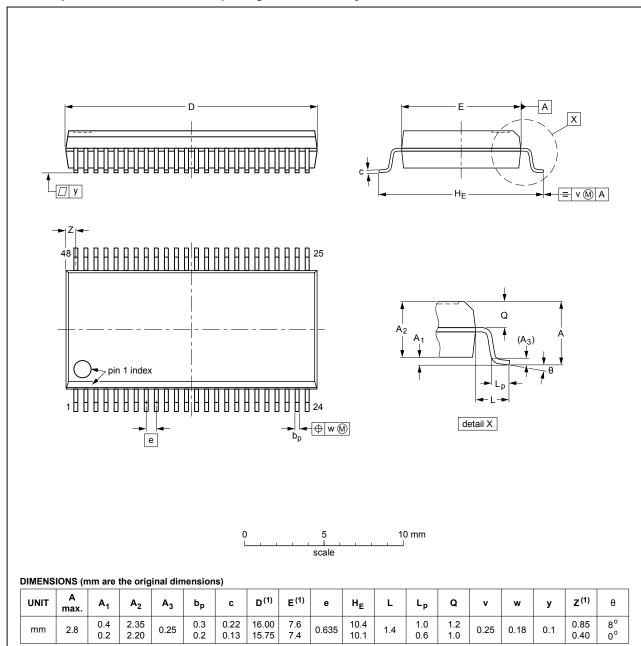
Direction	Supply voltage L		Load	Load		V _{EXT}		
	V _{CC(A)}	V _{CC(B)}	CL	R _L	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}	
nAn port to nBn port	2.3 V to 2.7 V	2.7 V to 3.6 V	50 pF	500 Ω	open	GND	2 × V _{CC}	
nBn port to nAn port	2.3 V to 2.7 V	2.7 V to 3.6 V	50 pF	500 Ω	open	GND	6.0 V	
nAn port to nBn port	2.7 V to 3.6 V	4.5 V to 5.5 V	50 pF	500 Ω	open	GND	2 × V _{CC}	
nBn port to nAn port	2.7 V to 3.6 V	4.5 V to 5.5 V	50 pF	500 Ω	open	GND	6.0 V	

Product data sheet

11. Package outline

SSOP48: plastic shrink small outline package; 48 leads; body width 7.5 mm

SOT370-1



Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT370-1		MO-118				99-12-27 03-02-19	

Fig. 7. Package outline SOT370-1 (SSOP48)

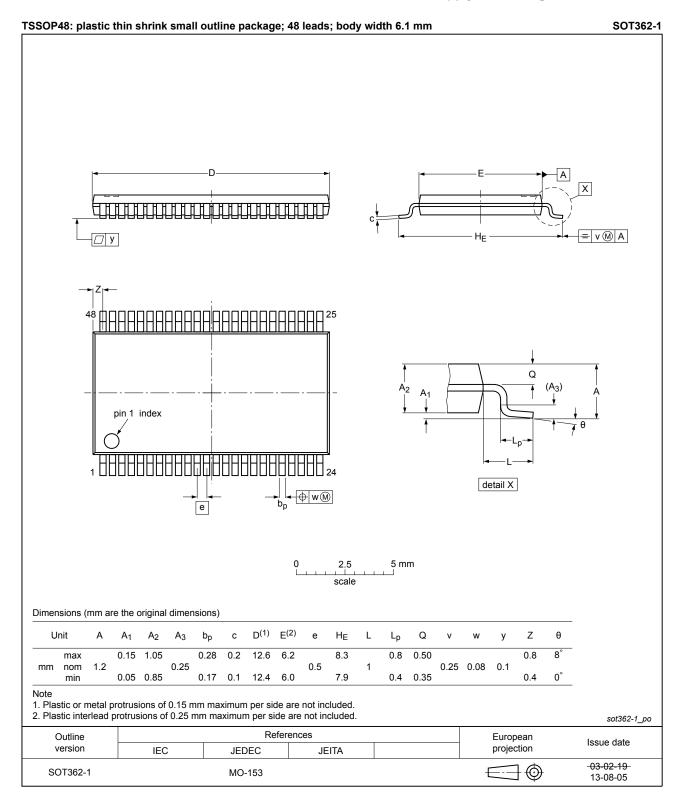


Fig. 8. Package outline SOT362-1 (TSSOP48)

12. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

13. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74ALVC164245 v.9	20181112	Product data sheet	-	74ALVC164245 v.8	
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Type number 74ALVC164245BX (SOT1134-2) removed. Package outline drawing SOT362-1 updated. 				
74ALVC164245 v.8	20120315	Product data sheet	-	74ALVC164245 v.7	
Modifications:	For type number 74ALVC164245BX the sot code has changed to SOT1134-2.				
74ALVC164245 v.7	20111117	Product data sheet	-	74ALVC164245 v.6	
Modifications:	Legal pages updated.				
74ALVC164245 v.6	20110616	Product data sheet	-	74ALVC164245 v.5	
74ALVC164245 v.5	20100413	Product data sheet	-	74ALVC164245 v.4	
74ALVC164245 v.4	20081111	Product data sheet	-	74ALVC164245 v.3	
74ALVC164245 v.3	20040914	Product data sheet	-	74ALVC164245 v.2	
74ALVC164245 v.2	20040601	Product data sheet	-	74ALVC164245 v.1	
74ALVC164245 v.1	19980826	Product specification	-	-	

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of Nexperia.

Right to make changes — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — Nexperia products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an Nexperia product can reasonably be expected to result in personal

16-bit dual supply translating transceiver; 3-state

injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nexperia.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific Nexperia product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Nexperia accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Nexperia's warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond Nexperia's specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Nexperia for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond Nexperia's standard warranty and Nexperia's product specifications.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

Contents

1. (General description	. 1
2. F	Features and benefits	. 1
3. (Ordering information	. 1
4. F	Functional diagram	2
5. F	Pinning information	.4
5.1.	Pinning	.4
5.2.	Pin description	. 4
6. F	unctional description	. 5
7. L	imiting values	. 5
8. F	Recommended operating conditions	6
9. 8	Static characteristics	6
10.	Dynamic characteristics	. 8
10.1	. Waveforms and test circuit	. 9
11.	Package outline	11
12.	Abbreviations	13
13.	Revision history	13
	Legal information	

For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 12 November 2018

[©] Nexperia B.V. 2018. All rights reserved